NSN 5961-00-578-8010

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-578-8010
Inclosure Material:
Metal
Overall Length:
0.210 inches
Overall Height:
0.220 inches
Overall Width:
0.140 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
5.9 reverse voltage, peak
Current Rating Per Characteristic:
5.00 milliamperes repetitive peak forward current
Power Rating Per Characteristic:
150.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:

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